

October 1995

6A, 1200V Ultrafast Dual Diode

Features

- Ultrafast with Soft Recovery <70ns
- Operating Temperature +175°C
- Reverse Voltage 1200V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Description

The RURP6120CC is an ultrafast dual diode with soft recovery characteristics ($t_{RR} < 70ns$). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

PACKAGE AVAILABILITY

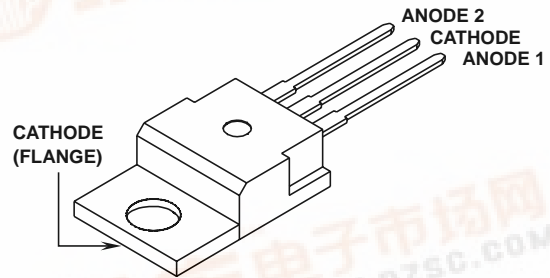
| PART NUMBER | PACKAGE | BRAND |
|-------------|----------|----------|
| RURP6120CC | TO-220AB | RUR6120C |

NOTE: When ordering, use the entire part number.

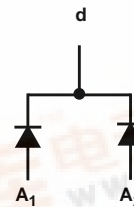
Formerly developmental type TA49039.

Package

JEDEC TO-220AB



Symbol



Absolute Maximum Ratings (per leg) $T_C = +25^\circ C$, Unless Otherwise Specified

| | RURP6120CC | UNITS |
|---|-------------|-------|
| Peak Repetitive Reverse Voltages V_{RRM} | 1200 | V |
| Working Peak Reverse Voltage V_{RWM} | 1200 | V |
| DC Blocking Voltage. V_R | 1200 | V |
| Average Rectified Forward Current $I_{F(AV)}$ $T_C = +140^\circ C$ | 6 | A |
| Repetitive Peak Surge Current. I_{FSM} Square Wave, 20kHz | 12 | A |
| Nonrepetitive Peak Surge Current I_{FSM} Halfwave, 1 phase, 60Hz | 60 | A |
| Maximum Power Dissipation P_D | 50 | W |
| Avalanche Energy (See Figures 10 and 11). E_{AVL} | 10 | mj |
| Operating and Storage Temperature T_{STG}, T_J | -65 to +175 | °C |

Specifications RURP6120CC

Electrical Characteristics (per leg) $T_C = +25^\circ\text{C}$, Unless Otherwise Specified

| SYMBOL | TEST CONDITION | RURP6120CC LIMITS | | | UNITS |
|-----------------|--|-------------------|-----|-----|---------------------------|
| | | MIN | TYP | MAX | |
| V_F | $I_F = 6\text{A}, T_C = +25^\circ\text{C}$ | - | - | 2.1 | V |
| | $I_F = 6\text{A}, T_C = +150^\circ\text{C}$ | - | - | 1.9 | V |
| I_R | $V_R = 1200\text{V}, T_C = +25^\circ\text{C}$ | - | - | 100 | μA |
| | $V_R = 1200\text{V}, T_C = +150^\circ\text{C}$ | - | - | 500 | μA |
| t_{RR} | $I_F = 1\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$ | - | - | 70 | ns |
| | $I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$ | - | - | 90 | ns |
| t_A | $I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$ | - | 45 | - | ns |
| t_B | $I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$ | - | 30 | - | ns |
| Q_{RR} | $I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$ | - | 400 | - | nC |
| C_J | $V_R = 10\text{V}, I_F = 0\text{A}$ | - | 22 | - | pF |
| $R_{\theta JC}$ | | - | - | 3 | $^\circ\text{C}/\text{W}$ |

DEFINITIONS

V_F = Instantaneous forward voltage ($p_w = 300\mu\text{s}$, $D = 2\%$).

I_R = Instantaneous reverse current.

t_{RR} = Reverse recovery time (See Figure 2), summation of $t_A + t_B$.

t_A = Time to reach peak reverse current (See Figure 2).

t_B = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 2).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

E_{AVL} = Controlled Avalanche Energy (See Figures 10 and 11).

p_w = pulse width.

D = duty cycle.

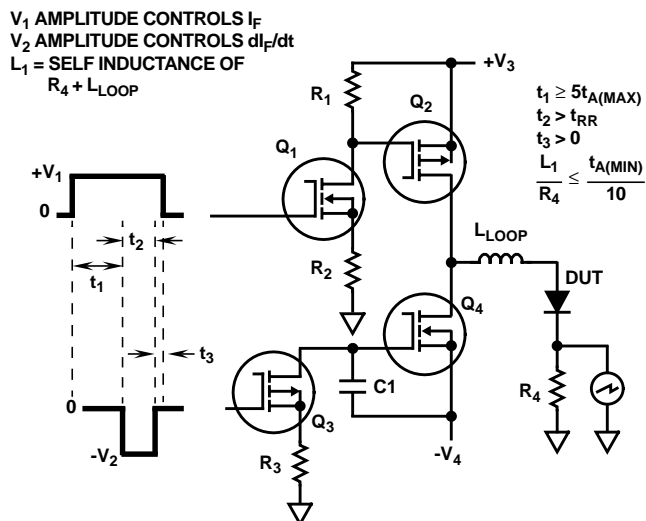


FIGURE 1. t_{RR} TEST CIRCUIT

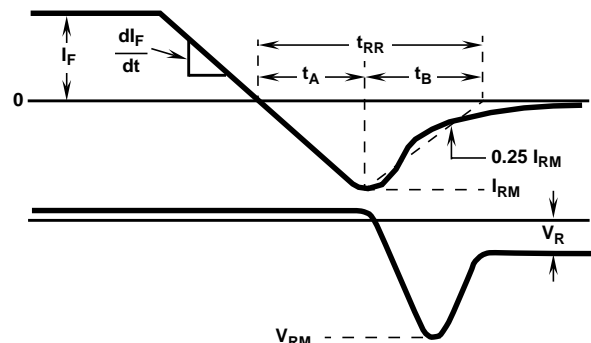


FIGURE 2. t_{RR} WAVEFORMS AND DEFINITIONS

RURP6120CC

Typical Performance Curves

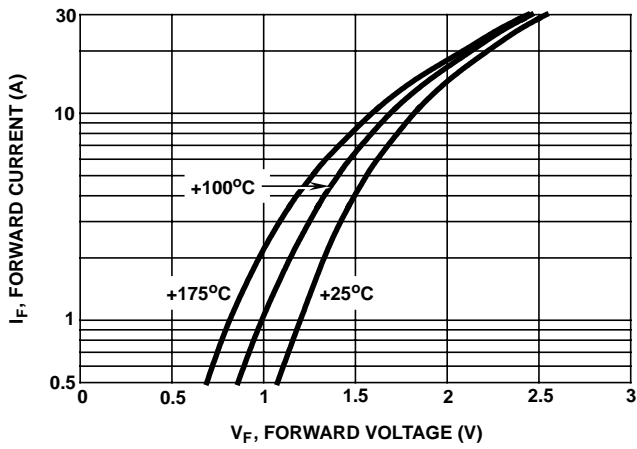


FIGURE 3. TYPICAL FORWARD CURRENT vs FORWARD VOLTAGE DROP

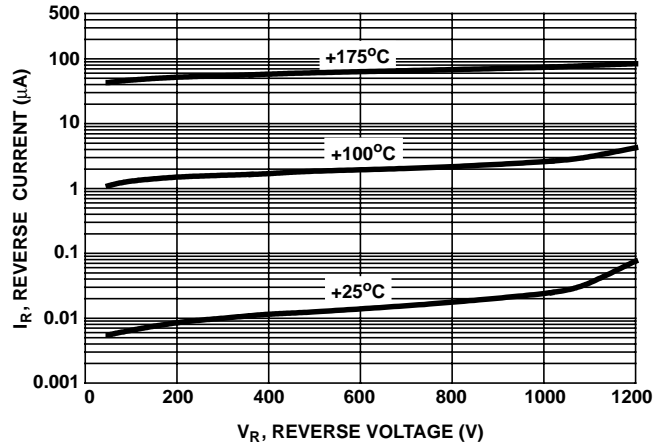


FIGURE 4. TYPICAL REVERSE CURRENT vs REVERSE VOLTAGE

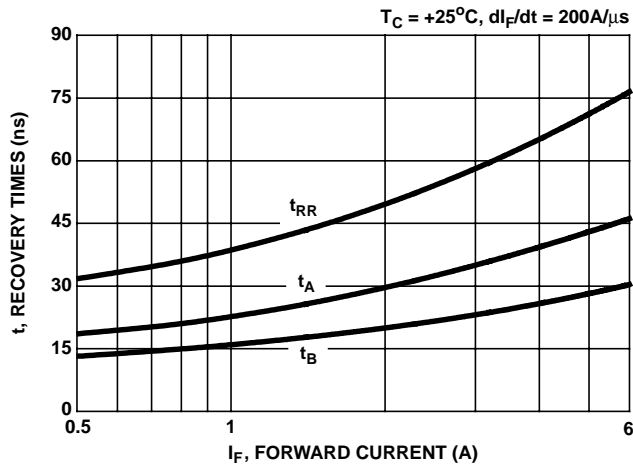


FIGURE 5. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT AT +25°C

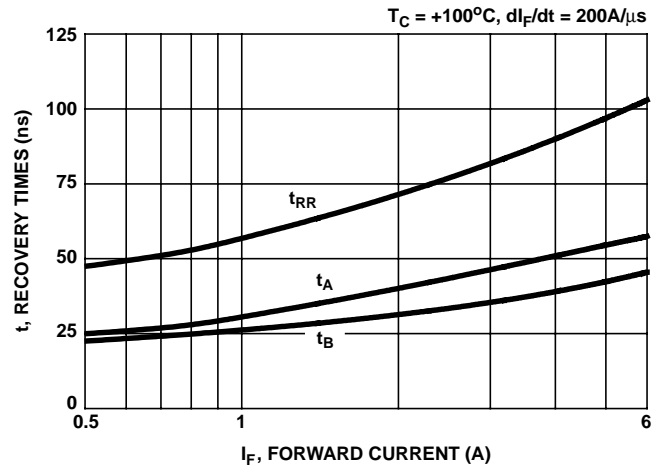


FIGURE 6. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT AT +100°C

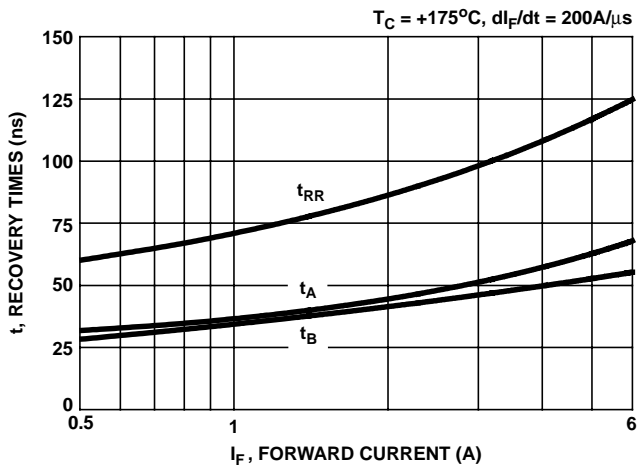


FIGURE 7. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT AT +175°C

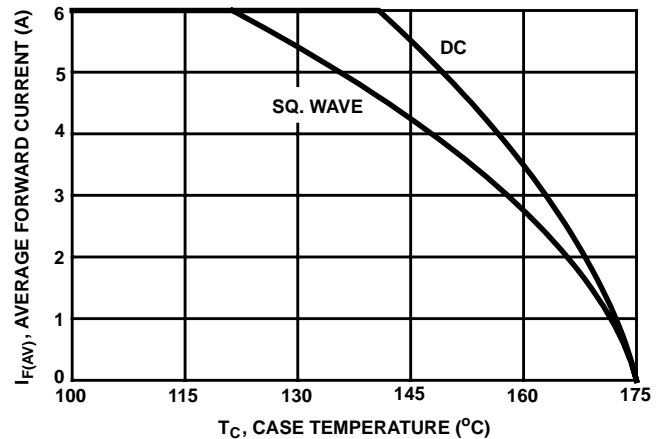


FIGURE 8. CURRENT DERATING CURVE

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Typical Performance Curves (Continued)

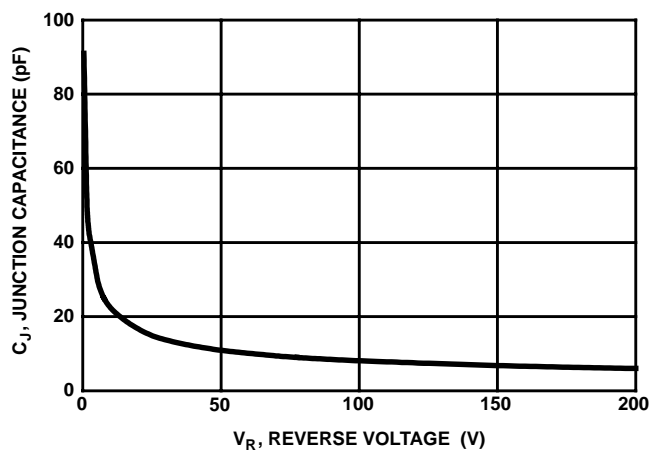


FIGURE 9. TYPICAL JUNCTION CAPACITANCE vs REVERSE VOLTAGE

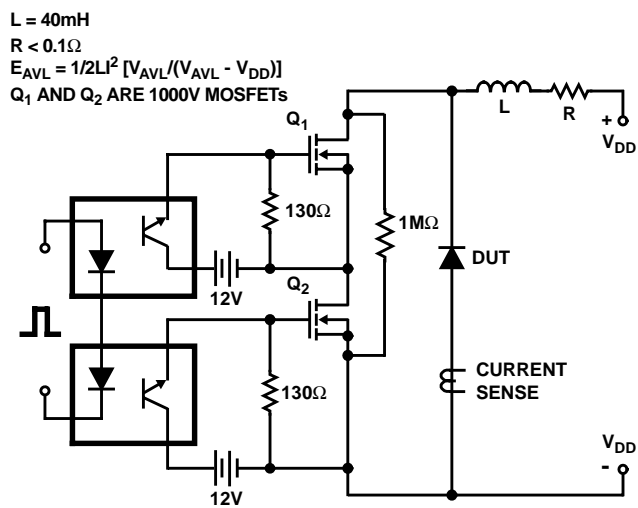


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

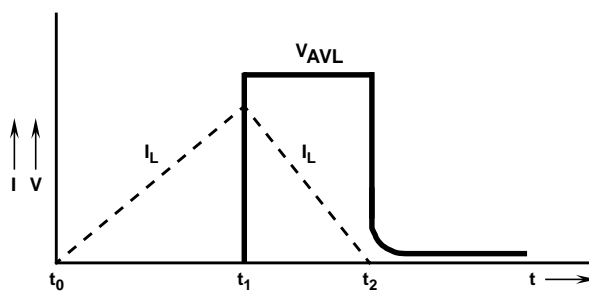
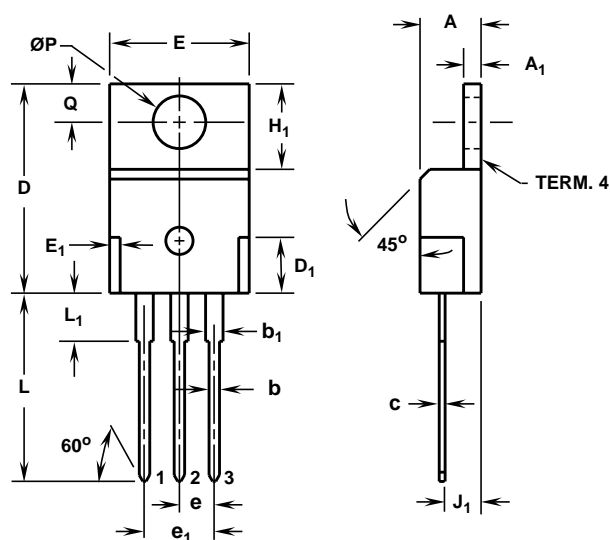


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

RURP6120CC

Plastic Packages



- LEAD 1. ANODE 1
- LEAD 2. CATHODE
- LEAD 3. ANODE 2
- TERM. 4. CATHODE

TO-220AB

3 LEAD JEDEC TO-220AB PLASTIC PACKAGE

| SYMBOL | INCHES | | MILLIMETERS | | NOTES |
|----------------|-----------|-------|-------------|-------|---------|
| | MIN | MAX | MIN | MAX | |
| A | 0.170 | 0.180 | 4.32 | 4.57 | - |
| A ₁ | 0.048 | 0.052 | 1.22 | 1.32 | - |
| b | 0.030 | 0.034 | 0.77 | 0.86 | 3, 4 |
| b ₁ | 0.045 | 0.055 | 1.15 | 1.39 | 2, 3 |
| c | 0.014 | 0.019 | 0.36 | 0.48 | 2, 3, 4 |
| D | 0.590 | 0.610 | 14.99 | 15.49 | - |
| D ₁ | - | 0.160 | - | 4.06 | - |
| E | 0.395 | 0.410 | 10.04 | 10.41 | - |
| E ₁ | - | 0.030 | - | 0.76 | - |
| e | 0.100 TYP | | 2.54 TYP | | 5 |
| e ₁ | 0.200 BSC | | 5.08 BSC | | 5 |
| H ₁ | 0.235 | 0.255 | 5.97 | 6.47 | - |
| J ₁ | 0.100 | 0.110 | 2.54 | 2.79 | 6 |
| L | 0.530 | 0.550 | 13.47 | 13.97 | - |
| L ₁ | 0.130 | 0.150 | 3.31 | 3.81 | 2 |
| ØP | 0.149 | 0.153 | 3.79 | 3.88 | - |
| Q | 0.102 | 0.112 | 2.60 | 2.84 | - |

NOTES:

1. These dimensions are within allowable dimensions of Rev. J of JEDEC TO-220AB outline dated 3-24-87.
2. Lead dimension and finish uncontrolled in L₁.
3. Lead dimension (without solder).
4. Add typically 0.002 inches (0.05mm) for solder coating.
5. Position of lead to be measured 0.250 inches (6.35mm) from bottom of dimension D.
6. Position of lead to be measured 0.100 inches (2.54mm) from bottom of dimension D.
7. Controlling dimension: Inch.
8. Revision 1 dated 1-93.

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